Revision 0.70



2017-08-23

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
780 nm DFB Laser	Spectroscopy (Rb D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	THz Generation
with PM Fiber, integrated μ -Isolator and Angled Physical Contact (AP	C)



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-15		70
Operational Temperature at Laser Chip	T_{LD}	°C	10		50
Forward Current	I _F	mA			200
Reverse Voltage	V_R	V			2
Output Power	P _{opt}	mW			20
TEC Current	I _{TEC}	Α			1.8
TEC Voltage	V_{TEC}	V			3.2

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	5		60
Operational Temperature at Laser Chip	T_{LD}	°C	15		45
Forward Current	I _F	mA			180
Output Power	P_{opt}	mW	3		10

Measurement Conditions / Comments
measured by integrated Thermistor

Characteristics at $T_{LD} = 25^{\circ}$ at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	779	780	781
Target Wavelength	λ_{T}	nm		780.24	
Linewidth (FWHM)	Δλ	MHz		0.6	1
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	20 pm		
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	$d\lambda$ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	

Measurem	ent Conditions / Comments

see images on page 4
reached within T_{LD} = 15 ° 45° C at 10 mW
> 10 GHz, at target wavelength
$P_{opt} = 10 \text{ mW}$



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Characteristics at T _{LD} = 25° at BOL				cont'd	
Parameter	Symbol	Unit	min	typ	max
Laser Current @ P _{opt} = 10 mW	I _{LD}	mA			180
Slope Efficiency	η	W/A		0.2	
Threshold Current	I _{th}	mA			70
Polarization Extinction Ratio	PER	dB		20	

Measurement Conditions / Comments
exfiber
$P_{opt} = 10 \text{ mW}$

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μA/mW	5		100

Meas	urement Conditions / Comments
$U_R =$	5 V

Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		1.5	
Power Dissipation (total loss at case)	P _{loss}	W		0.5	
Temperature Difference	ΔΤ	K			45

Measurement Conditions / Comments
$P_{opt} = 10 \text{ mW}, \Delta T = 30 \text{ K}$
$P_{opt} = 10 \text{ mW}, \Delta T = 30 \text{ K}$
$P_{opt} = 10 \text{ mW}, \Delta T = 30 \text{ K}$
$P_{opt} = 10 \text{ mW}, \Delta T = Tcase - TLD $

Symbol	Unit	min	typ	max
R	kΩ		10	
β			3892	
А			1.1293 x 10	-3
В			2.3410 x 10	-4
C			8.7755 x 10	-8
	R β A	R kΩ β A	R kΩ β A B	R kΩ 10 β 3892 A 1.1293 x 10

Thermistor (Standard NTC Type)

Measurement Conditions / Comments				
$T_{LD} = 25^{\circ} C$				
$R_1 / R_2 = e^{ \beta (1/T_1 \cdot 1/T_2)} $ at $T_{LD} =$	0° 50° C			
$1/T = A + B(\ln R) + C(\ln R)^3$				
T: temperature in Kelvin				
R: resistance at T in Ohm				

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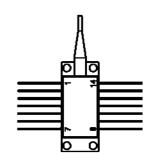
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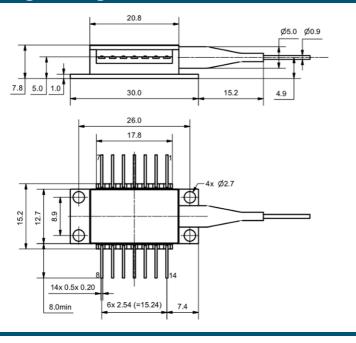


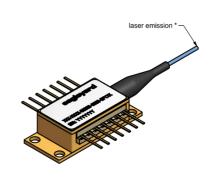
Pin Assignment

1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected
Pins	are isolated from case unless noted otherwise.		



Package Drawings

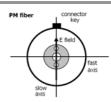




Fiber and Connector Type

PM Fiber	900 / 125 / 5.5 μ m, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	different variants available

Measurement Conditions / Comments



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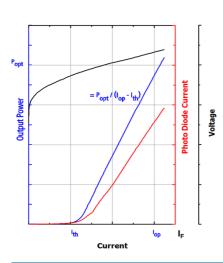
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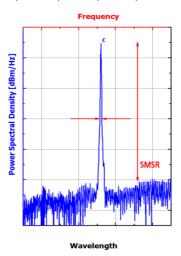


Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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